

YJ Planar Schottky Barrier Diode Die Specification

200V 3A, 60mil, Schottky barrier diode die based on silicon planar process

Part No.: PSB060H200SS-280A

Main Products Characteristics

- Average forward current: $I_{F(AV)} = 3A$
- Maximum operating junction temperature: $T_j = 175\text{ }^{\circ}C$